

**Measurement condition**

Ambient temperature: 23 °C  
 Input power level: 0 dBm  
 Terminating impedance: \*  
     Input: 614 Ω || -12.2 pF  
     Output: 766 Ω || -10.3 pF

**Characteristics**

Remark:

The reference level for the relative attenuation  $a_{rel}$  of the TFS159B is the minimum of the pass band attenuation. This value is defined as the insertion loss  $a_e$ . The nominal frequency  $f_N$  is fixed at 159.4 MHz without any tolerance. The values of relative attenuation  $a_{rel}$  are guaranteed for the whole operating temperature range. The frequency shift of the filter in the operating temperature range is included in the production tolerance scheme.

<b>D a t a</b>		<b>typ. value</b>		<b>tolerance / limit</b>	
<b>Insertion loss</b> (reference level)	$a_e$	23	dB	max.	24 dB
<b>Nominal frequency</b>	$f_N$				159.4 MHz
<b>Passband</b>	PB			$f_N \pm 2.65$	MHz
<b>Passband 1</b>	PB1 ***			$156.775 \pm 0.025$	MHz
<b>Passband 2</b>	PB2 ***			$156.825 \pm 0.025$	MHz
<b>Passband 3</b>	PB3 ***			$161.975 \pm 0.025$	MHz
<b>Passband 4</b>	PB4 ***			$162.025 \pm 0.025$	MHz
<b>Amplitude variation</b> (at only 25°C) between PB1, PB2, PB3, PB4		0.24	dB	max.	0.6 dB
<b>Amplitude variation</b> between PB1, PB2, PB3, PB4		0.5	dB	max.	1 dB
<b>Passband ripple within</b> PB1, PB2, PB3, PB4	p-p	0.02	dB	max.	0.2 dB
<b>Relative attenuation</b>	$a_{rel}$				
$f_N$ ... $f_N \pm 2.65$ MHz (at only 25°C)		0.24	dB	max.	0.6 dB
$f_N$ ... $f_N \pm 2.65$ MHz		0.5	dB	max.	1 dB
$f_N \pm 3.6$ MHz ... $f_N \pm 20$ MHz		47	dB	min.	40 dB
<b>Phase ripple within</b> PB1, PB2, PB3, PB4		0.1	°	max.	1.5 °
<b>Group delay ripple within</b> PB1, PB2, PB3, PB4		20	ns	max.	100 ns
<b>Return loss within</b> PB		10	dB	min.	4 dB
<b>Input Power</b>		-	dB	max.	20 dBm
<b>Operating temperature range</b>	OTR				- 10 °C ... + 65 °C
<b>Storage temperature range</b>					- 45 °C ... + 125 °C
<b>Temperature coefficient of frequency</b>	$TC_f$ **	-0.036	ppm/K <sup>2</sup>		-

\*) The terminating impedances depend on parasites and q-values of matching elements and the board used, and are to be understood as reference values only. Should there be additional questions do not hesitate to ask for an application note or contact our design team.

\*\*)  $\Delta f(\text{Hz}) = TC_f(\text{ppm/K}^2) \times (T-T_0)^2 \times f$  (MHz), where  $T_0$  is typically 25°C.

\*\*\*) PB1, PB2, PB3, PB4 passbands have been extended to  $\pm 25$  kHz, from  $\pm 12.5$  kHz, to allow for doppler shifts.

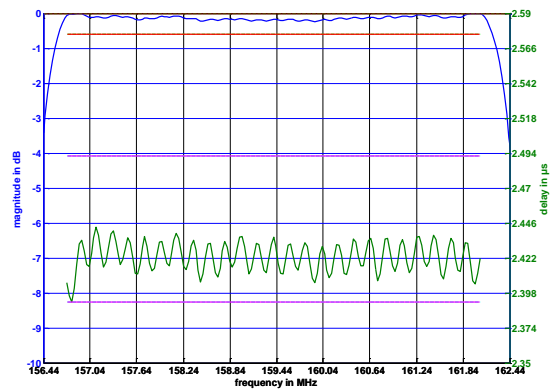
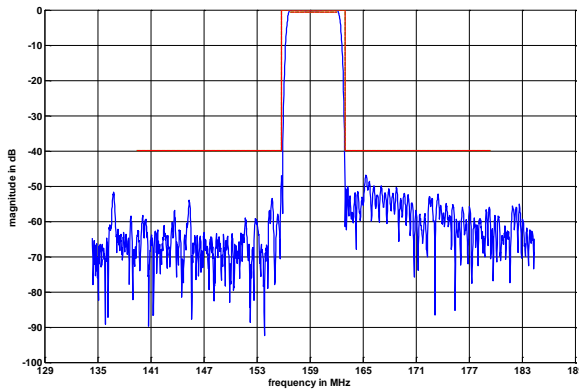
**Generated:**

**Checked / Approved:**

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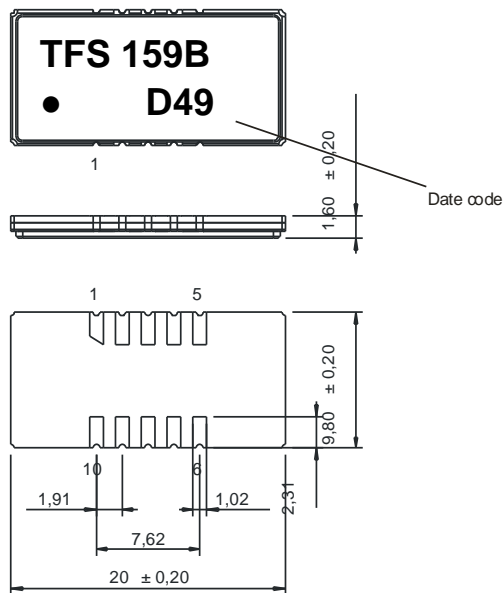
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Filter characteristic



Construction and pin connection

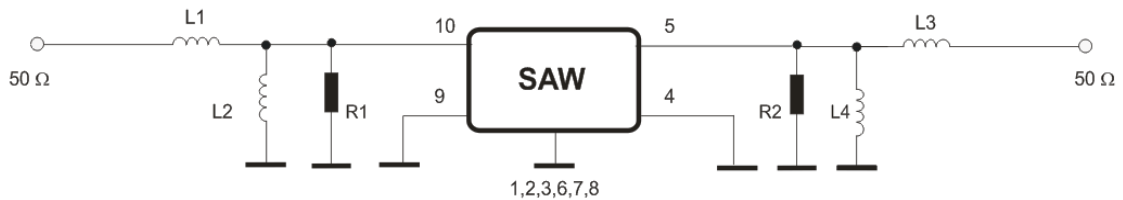
(All dimensions in mm)



- 1 Ground
- 2 Ground
- 3 Ground
- 4 Output RF Return
- 5 Output
- 6 Ground
- 7 Ground
- 8 Ground
- 9 Input RF Return
- 10 Input

Date code: Year + week  
 D 2013  
 E 2014  
 F 2015  
 ...

50 Ohm Test circuit



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**Stability characteristics, reliability**

After the following tests the filter shall meet the whole specification:

1. Shock: 500g, 1 ms, half sine wave, 3 shocks each plane;  
DIN IEC 68 T2 - 27
2. Vibration: 10 Hz to 500 Hz, 0.35 mm or 5 g respectively, 1 octave per min, 10 cycles per plane, 3 planes;  
DIN IEC 68 T2 - 6
3. Change of temperature: -55 °C to 125°C / 15 min. each / 100 cycles  
DIN IEC 68 part 2 – 14 Test N
4. Resistance to solder heat (reflow): reflow possible: three times max.;  
for temperature conditions refer to the attached "Air reflow temperature conditions" on page 4;
5. ESD ANSI/ESD S20.20-1999, class 1A for HBM

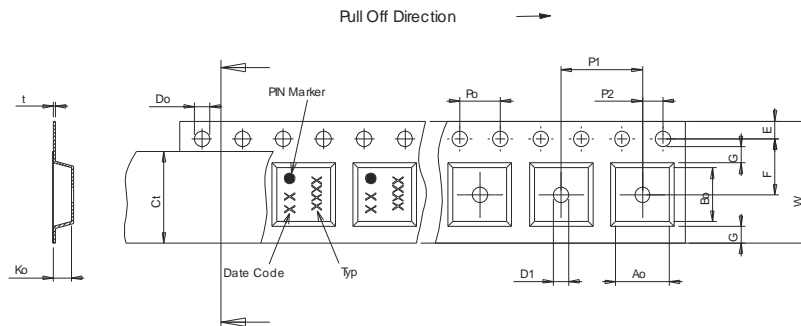
This filter is RoHS compliant (2011/65/EU)

**Packing**

- Tape & Reel: IEC 286 – 3, with exception of value for N and minimum bending radius;  
tape type II, embossed carrier tape with top cover tape on the upper side;
- max. pieces of filters per reel:  
reel of empty components at start: min. 300 mm  
reel of empty components at start including leader: min. 500 mm  
trailer: min. 300 mm

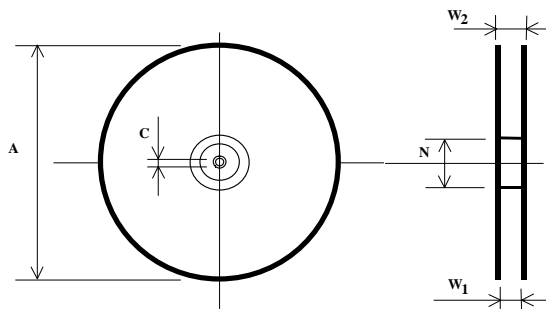
**Tape (all dimensions in mm)**

- W : 32.00
- Po : 4.00 ± 0.1
- Do : 1.50 +0.1/-0
- E : 1.75 ± 0.1
- F : 14.20 ± 0.1
- G(min) :
- P2 : 2.00 ± 0.1
- P1 : 16.00 ± 0.1
- D1(min) : 2.00
- Ao : 10.25 ± 0.1
- Bo : 20.45
- Ct : 25.5



**Reel (all dimensions in mm)**

- A : 330
- W1 : 32.4
- W2(max) : 38.4
- N(min) : 100
- C : 13.0



The minimum bending radius is 45 mm.

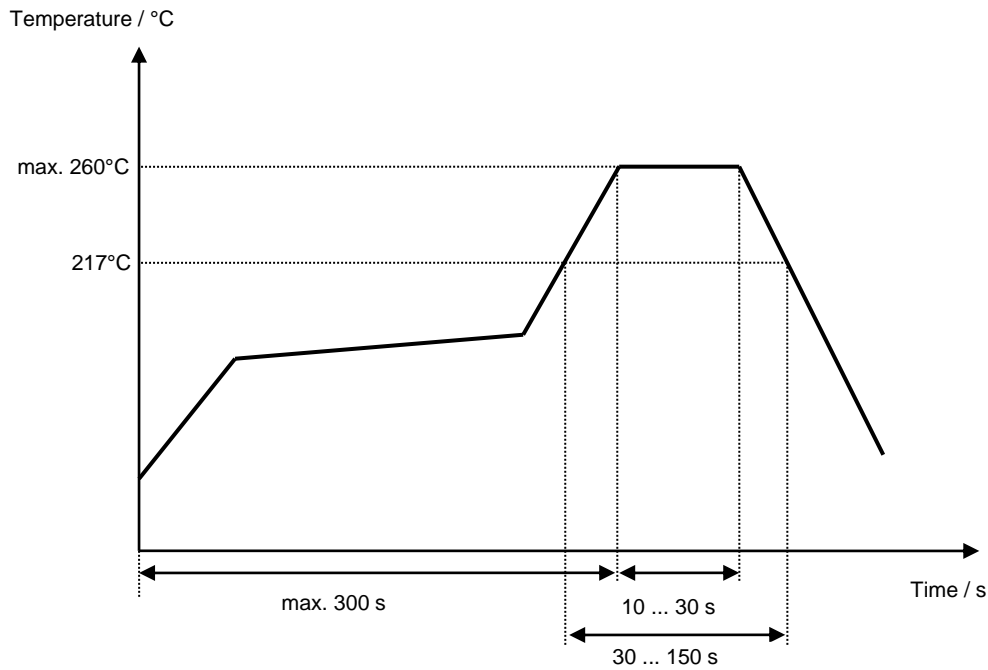
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**Air reflow temperature conditions**

<b>Conditions</b>	<b>Exposure</b>
Average ramp-up rate (30°C to 217°C)	less than 3°C/second
> 100°C	between 300 and 600 seconds
> 150°C	between 240 and 500 seconds
> 217°C	between 30 and 150 seconds
Peak temperature	max. 260°C
Time within 5°C of actual peak temperature	between 10 and 30 seconds
Cool-down rate (Peak to 50°C)	less than 6°C/second
Time from 30°C to Peak temperature	no greater than 300 seconds

**Chip-mount air reflow profile**



**History**

<b>Version</b>	<b>Reason of Changes</b>	<b>Name</b>	<b>Date</b>
1.0	- Generation of development specification	TCUK	13.09.2013
1.1	- Add typ values, test circuit uses L-L match and move development to filter specification.	TCUK	18.12.2013